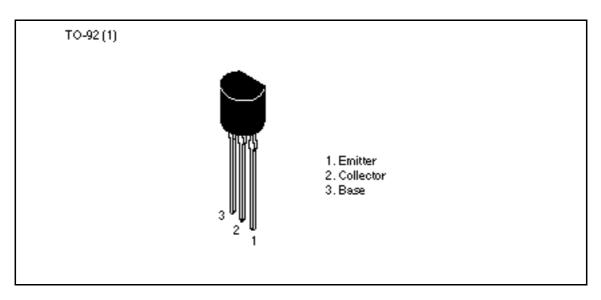
## Silicon PNP Epitaxial

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#### Application

- Low frequency amplifier
- Complementary pair with 2SC2396, 2SC2543 and 2SC2544

#### Outline





### **Absolute Maximum Ratings** (Ta = $25^{\circ}$ C)

Item	Symbol	2SA1025	2SA1081	2SA1082	Unit
Collector to base voltage	$V_{\text{CBO}}$	-60	-90	-120	V
Collector to emitter voltage	$V_{ceo}$	-60	-90	-120	V
Emitter to base voltage	$V_{EBO}$	-5	-5	-5	V
Collector current	I <sub>c</sub>	-100	-100	-100	mA
Emitter current	I <sub>E</sub>	100	100	100	mA
Collector power dissipation	Pc	400	400	400	mW
Junction temperature	Tj	150	150	150	°C
Storage temperature	Tstg	-55 to +150	-55 to +150	-55 to +150	°C

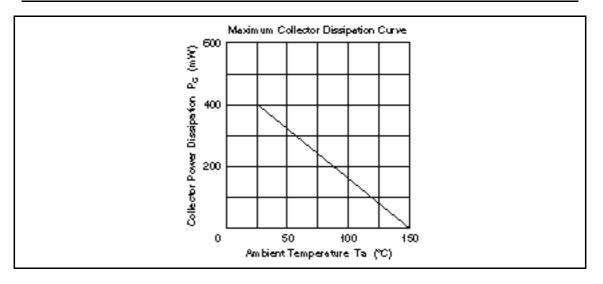
### **Electrical Characteristics** (Ta = 25°C)

		2SA1025			2SA1	2SA1081 2SA1		1082				
Item	Symbol	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit	Test conditions
Collector to base breakdown voltage	V <sub>(BR)CBO</sub>	-60	_	_	-90	_	_	-120	_	_	V	$I_{c} = -10 \ \mu A, \ I_{E} = 0$
Collector to emitter breakdown voltage	V <sub>(BR)CEO</sub>	-60	_	—	-90	—	_	-120	—	_	V	I <sub>c</sub> = -1 mA, R <sub>BE</sub> =
Emitter to base breakdown voltage	$V_{(BR)EBO}$	-5	_	—	-5	_	_	-5	—	—	μA	$I_{\rm E} = -10 \ \mu A, \ I_{\rm C} = 0$
Collector cutoff current	I <sub>CBO</sub>	—	_	-0.1	—	—	-0.1	_	—	-0.1	μA	$V_{CB} = -50 \text{ V}, I_{E} = 0$
Emitter cutoff current	$I_{\text{EBO}}$	—	—	-0.1	_	—	-0.1	—	—	-0.1		$V_{EB} = -2 V, I_{C} = 0$
DC current transfer ratio	h <sub>FE</sub> *1	250	_	800	250	_	800	250	_	800		$V_{CE} = -12 \text{ V},$ $I_{C} = -2 \text{ mA}$
Collector to emitter saturation voltage	$V_{\text{CE(sat)}}$	_	_	-0.2	_	_	-0.2	_	_	-0.2	V	$I_c = -10 \text{ mA},$ $I_B = -1 \text{ mA}$
Base to emitter voltage	$V_{BE}$	_	-0.6	_	_	-0.6	_	_	-0.6	_	V	$V_{CE} = -12 \text{ V},$ $I_{C} = -2 \text{ mA}$
Gain bandwidth product	f <sub>T</sub>	_	90	_	_	90	_	_	90	_	MHz	$V_{CE} = -12 \text{ V},$ $I_{C} = -2 \text{ mA}$
Collector output capacitance	Cob	_	3.5	_	_	3.5	_		3.5	_	рF	$V_{CB} = -10 \text{ V}, \text{ I}_{E} = 0,$ f = 1 MHz
Note: 1. The 2SA1025, 2SA1081 and 2SA1082 are grouped by h <sub>FE</sub> as follows.   D E												

250 to 500 400 to 800

See characteristic curves of 2SA1083.

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